

800mA, 24V, Rail-to-Rail I/O

High Output Current Operational Amplifiers

Features

- Peak Output Current: 800mA
- High Slew Rate: 40V/ μ s
- 55 MHz @ -3dB bandwidth
- Single or Dual Supply Operation:
 - 4.5V ~ 24V
 - ± 2.25 V ~ ± 12 V
- Rail-to-Rail Input and Output (RRIO)
- Low Quiescent Current: 2.3mA
- Unity Gain Stable
- No Phase Reversal
- Over Current Protection
- Over Temperature Protection
- Output Short Protection
- Extended Temperature Ranges
From -40°C to +125°C
- Small Packaging:
DFN3x3-8/SOP8-EP/SOP8

Applications

- Audio Applications
- Twisted-pair Line Drivers
- LCD TVs
- Monitors
- Laptops
- TFT-LCD Panels

General Description

The COS8416 (dual) comprises two high slew rate, voltage feedback amplifiers. The output stage is capable of delivering 800mA peak current. The COS8416 operates on single supply from 4.5V to 24V or dual supplies from ± 2.25 V to ± 12 V. They have bandwidth and slew rate typically found in current feedback amplifiers. The wide bandwidth and fast slew rate make these amplifiers useful in many general purpose, high speed applications.

The COS8416 provides excellent overall performance and versatility. The output voltage swing extends to within 0.5V of each rail while driving a 50 Ω load, providing the maximum output dynamic range with excellent overdrive recovery. The features make the COS8416 ideal for applications that require a large signal swing into a heavy load.

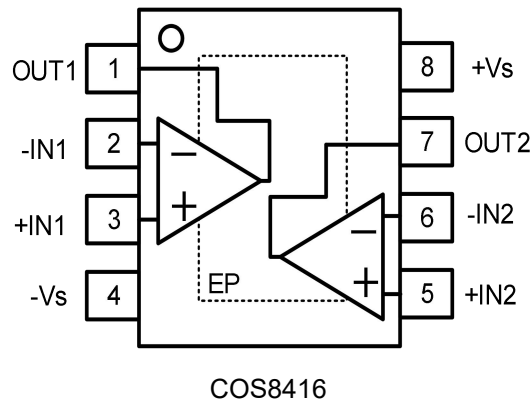
The COS8416 is available in Green DFN3x3-8, SOP8 and SOP8-EP (Exposed Pad) package.

Rev1.1

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1. Pin Configuration and Functions



Pin Functions

Name	Description	Note
+Vs	Positive power supply	A bypass capacitor of 0.1 μ F as close to the part as possible should be placed between power supply pins or between supply pins and ground.
-Vs	Negative power supply or ground	If it is not connected to ground, bypass it with a capacitor of 0.1 μ F as close to the part as possible.
-IN	Negative input	Inverting input of the amplifier. Voltage range of this pin can go from -Vs -0.3V to +Vs + 0.3V.
+IN	Positive input	Non-inverting input of the amplifier. This pin has the same voltage range as -IN.
OUT	Output	The output voltage range extends to within millivolts of each supply rail.
EP	Exposed Thermal Pad	Connect to -Vs or ground

2. Ordering Information

Channel	Model	Package	Order Number	Package Option	Marking Information
2	COS8416	SOP-8-EP	COS8416SRE	Tape and Reel, 4000	COS8416
		SOP-8	COS8416SR	Tape and Reel, 4000	COS8416
		DFN3x3-8	COS8416DN	Tape and Reel, 4000	COS8416

3. Product Specification

3.1 Absolute Maximum Ratings ⁽¹⁾

Parameter	Rating	Units
Power Supply: +Vs to -Vs	25	V
Input Voltage	-Vs -0.5V to +Vs + 0.5V	V
Input Current ⁽²⁾	10	mA
Storage Temperature Range	-65 to 150	°C
Junction Temperature	150	°C
Operating Temperature Range	-40 to 125	°C
ESD Susceptibility, HBM	2000	V

(1) Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

(2) Input terminals are diode-clamped to the power-supply rails. Input signals that can swing more than 0.5V beyond the supply rails should be current-limited to 10mA or less.

3.2 Thermal Data

Parameter	Rating	Unit
Package Thermal Resistance, $R_{\theta JA}$ (Junction-to-ambient)	155 (SOP8) 47 (SOP8-EP) 43 (DFN8-3x3)	°C/W

3.3 Recommended Operating Conditions

Parameter	Rating	Unit
DC Supply Voltage	4.5 (± 2.25) ~ 24 (± 12)	V
Operating ambient temperature	-40 ~ +125	°C

3.4 Electrical Characteristics

($+V_S=24V$, $-V_S=0$, $V_{CM}=+V_S/2$ and $R_L=25\Omega$. Typical value are at $T_A=+25^\circ C$, unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input Characteristics						
Input Offset Voltage	V _{OS}			±2	±10	mV
Input Offset Voltage Drift	ΔV _{OS} /ΔT	-40 to 125°C		±5		μV/°C
Input Bias Current	I _B			-	±1	nA
Input Offset Current	I _{OS}			-	±1	nA
Common-Mode Voltage Range	V _{CM}		-V _S -0.1		+V _S +0.1	V
Common-Mode Rejection Ratio	CMRR	-V _S -0.1V≤V _{OUT} ≤+V _S +0.1V	60	80		dB
Open-Loop Voltage Gain	A _{OL}	-V _S +0.5V≤V _{OUT} ≤+V _S -0.5V		120		dB
Output Characteristics						
Output Voltage Swing from Rail	V _{OL}	Output Swing Low, I _L = -50mA		0.1		V
	V _{OH}	Output Swing High, I _L = 50mA		+V _S -0.17		V
Short-Circuit Current	I _{SR}	Sourcing		800		mA
	I _{SK}	Sinking		800		
Continuous Output Current	I _{CSR}	Sourcing		300		mA
	I _{CSK}	Sinking		300		
Power Supply						
Operating Voltage Range	V _S		4.5		24	V
			±2.25		±12	
Quiescent Current / Amplifier	I _Q	No load		2.3		mA
Power Supply Rejection Ratio	PSRR	V _S = 4.5V to 24V, V _{CM} = +V _S /2	70	90		dB
Dynamic Performance						
-3 dB Small-Signal Bandwidth	f _{-3dB}	G = +1, R _L =100Ω, C _L =10pF		55		MHz
Gain-Bandwidth Product	GBP	R _L =100Ω, C _L =10pF		25		MHz
Slew Rate	SR	G = +1 , 4V Step, R _L =100Ω, C _L =10pF		40		V/μs

Thermal Protection						
Thermal Shutdown Temperature	T_{SHDN}			150		°C
Thermal Shutdown Hysteresis	ΔT_{SHDN}			30		°C

4.0 Application Notes

Driving Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback op amps. As the load capacitance increases, the feedback loop's phase margin decreases, and the closed loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response. A unity gain buffer ($G = +1$) is the most sensitive to capacitive loads, but all gains show the same general behavior.

When driving large capacitive loads with these op amps (e.g., $> 100 \text{ pF}$ when $G = +1$), a small series resistor at the output (R_{ISO} in Figure 1) improves the feedback loop's phase margin (stability) by making the output load resistive at higher frequencies. It does not, however, improve the bandwidth.

To select R_{ISO} , check the frequency response peaking (or step response overshoot) on the bench. If the response is reasonable, you do not need R_{ISO} . Otherwise, start R_{ISO} at $1 \text{ k}\Omega$ and modify its value until the response is reasonable.

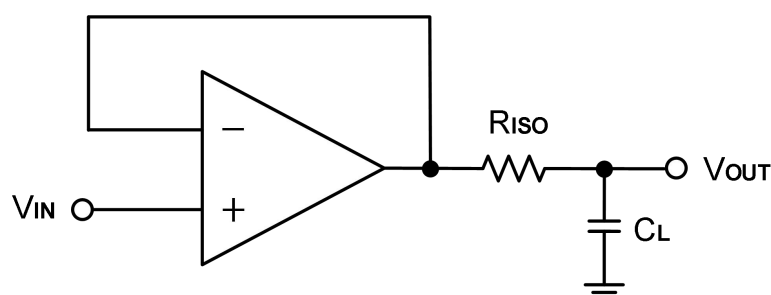


Figure 1. Indirectly Driving Heavy Capacitive Load

An improvement circuit is shown in Figure 2. It provides DC accuracy as well as AC stability. R_F provides the DC accuracy by connecting the inverting signal with the output, C_F and R_{ISO} serve to counteract the loss of phase margin by feeding the high frequency component of the output signal back to the amplifier's inverting input, thereby preserving phase margin in the overall feedback loop.

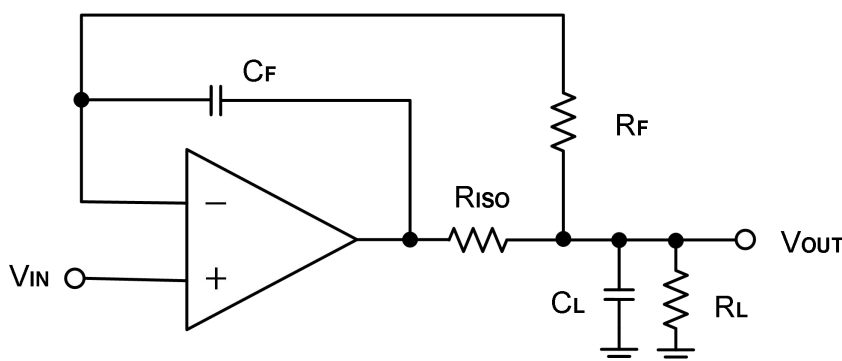


Figure 2. Indirectly Driving Heavy Capacitive Load with DC Accuracy

For the inverting configuration, there are two others ways to increase the phase margin: (a) by increasing the amplifier's gain or (b) by placing a capacitor in parallel with the feedback resistor to counteract the parasitic capacitance associated with inverting node, as shown in Figure 3.

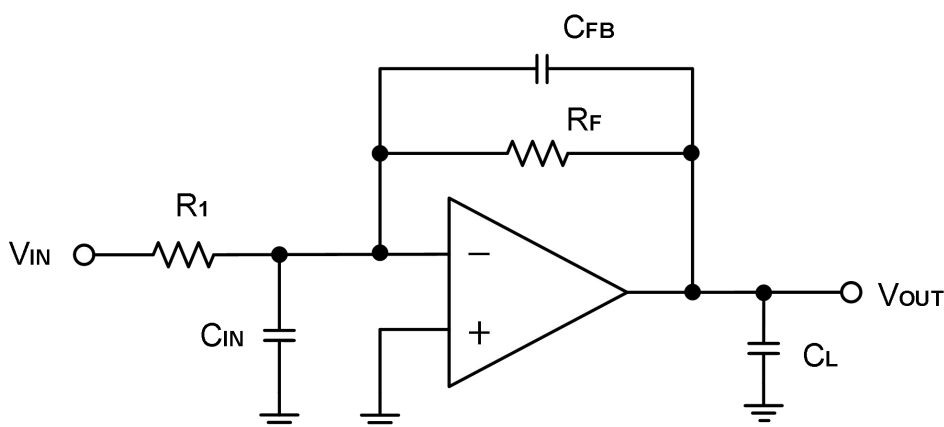


Figure 3. Adding a Feedback Capacitor in the inverting Configuration

Power-Supply Bypassing and Layout

The COS8416 operates from a single +4.5V to +24V supply or dual $\pm 2.25V$ to $\pm 12V$ supplies. For single-supply operation, bypass the power supply +Vs with a 0.1 μF ceramic capacitor which should be placed close to the +Vs pin. For dual-supply operation, both the +Vs and the -Vs supplies should be bypassed to ground with separate 0.1 μF ceramic capacitors. 2.2 μF tantalum capacitor can be added for better performance.

The length of the current path is directly proportional to the magnitude of parasitic inductances and thus the high frequency impedance of the path. High speed currents in an inductive ground return create an unwanted voltage noise. Broad ground plane areas will reduce the parasitic inductance. Thus a ground plane layer is important for high speed circuit design.

Typical Application Circuits

Differential Amplifier

The circuit shown in Figure 4 performs the differential function. If the resistors ratios are equal ($R_4 / R_3 = R_2 / R_1$), then $V_{OUT} = (V_{IP} - V_{IN}) \times R_2 / R_1 + V_{REF}$.

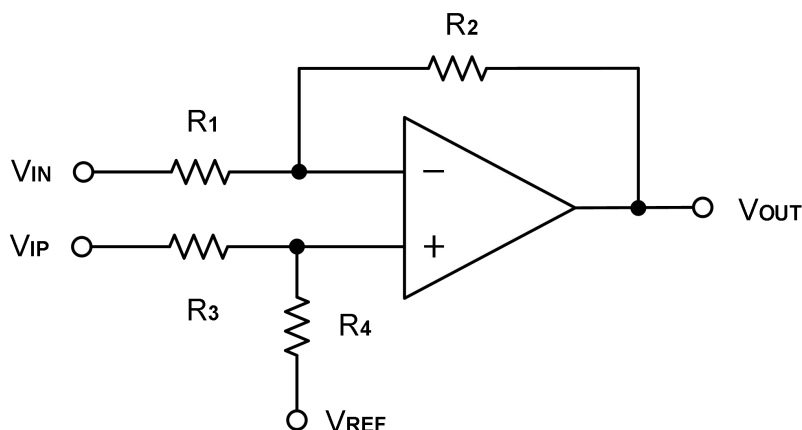


Figure 4. Differential Amplifier

Low Pass Active Filter

When receiving low-level signals, limiting the bandwidth of the incoming signals into the system is often required. The simplest way to establish this limited bandwidth is to place an RC filter at the noninverting terminal of the amplifier. If even more attenuation is needed, a multiple pole filter is required. The Sallen-Key filter can be used for this task, as Figure 5. For best results, the amplifier should have a bandwidth that is 8 to 10 times the filter frequency bandwidth. Failure to follow this guideline can result in reduction of phase margin. The large values of feedback resistors can couple with parasitic capacitance and cause undesired effects such as ringing or oscillation in high-speed amplifiers. Keep resistors value as low as possible and consistent with output loading consideration.

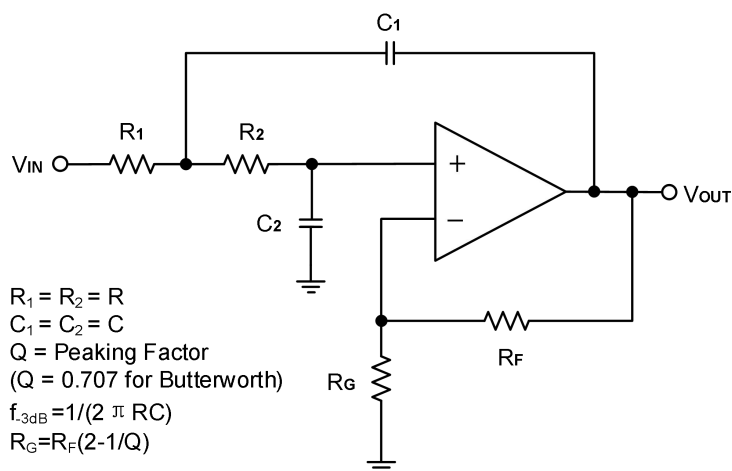
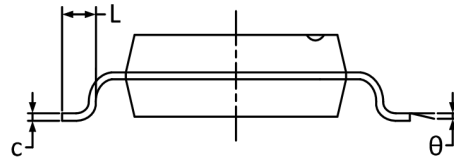
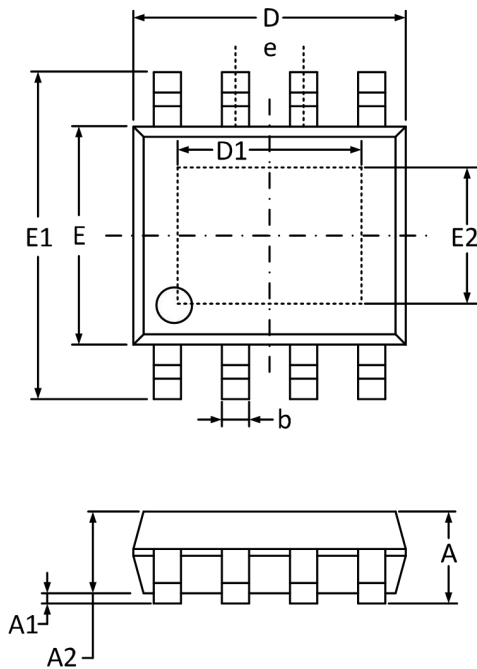


Figure 5. Two-Pole Low-Pass Sallen-Key Active Filter

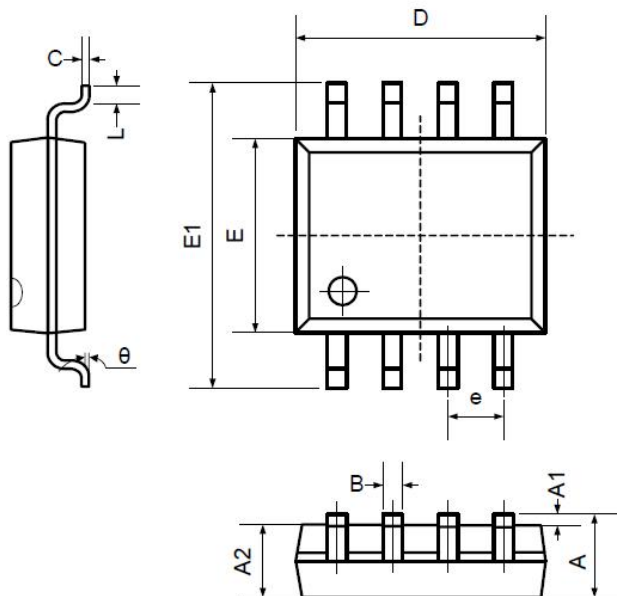
5. Package Information

5.1 SOP-8-EP (Exposed Package, Package Outline Dimensions)



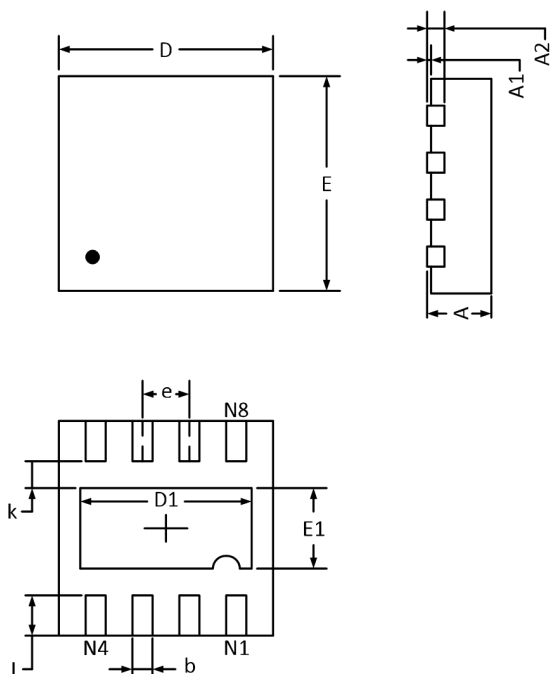
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A		1.700		0.067
A1	0.000	0.100	0.000	0.004
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.007	0.010
D	4.700	5.100	0.185	0.201
D1	3.202	3.402	0.126	0.134
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
E2	2.313	2.513	0.091	0.099
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

5.2 SOP-8 (Package Outline Dimensions)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
B	0.330	0.510	0.013	0.020
C	0.190	0.250	0.007	0.010
D	4.780	5.000	0.188	0.197
E	3.800	4.000	0.150	0.157
E1	5.800	6.300	0.228	0.248
e	1.270TYP		0.050TYP	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

5.3 DFN-8(3x3) (Package Outline Dimensions)



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	2.200	2.400	0.087	0.094
E	2.900	3.100	0.114	0.122
E1	1.400	1.600	0.055	0.063
k	0.200 MIN		0.008 MIN	
b	1.800	2.000	0.007	0.012
e	0.650 TYP		0.026 TYP	
L	0.375	0.575	0.015	0.023

6. Related Parts

Part Number	Description
COS6042	24kHz, 0.5μA, Nano-Power Op Amps, 1.4V to 5.5V Supply
COS8042	170MHz, 6.1mA, High Speed Op Amps, 3.2V to 24V Supply
COS2172	10MHz, 1.2mA, RRIO Op Amps, 4.5 to 40V Supply
COS2333	350kHz, 18μA, Precision Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10μV
COS8552	1.5MHz, 55μA, Precision Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10μV
COS2388	9MHz, 570μA, Precision Op Amps, 1.8 to 5.5V Supply, Zero Drift, Vos<10μV
COS2227	10MHz, 1.3mA, Precision Op Amps, 4.5 to 312V Supply, Vos<50μV
COS2182	5MHz, 580μA, RRIO Precision Op Amps, 4.5 to 40V Supply, Vos<50μV
COS620	1.5MHz, 1.3mA, Instrumentation Amps, 4.5 to 312V Supply, Vos<50μV
COSINA333	150kHz, 65μA, Instrumentation Amps, 1.8 to 5.5V Supply, Vos<25μV